



Tailoring of Physical Properties and Bio-Interactions on Semiconductors



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Introduction

- Nanostructures (~10⁻⁹m) grown on Wide Band Gap (TiO₂, ZnO, etc.) semiconductors have shown potential applications in Memory Devices, Transparent Conducting Oxides, Spintronics, Solar Cells, etc.
- Depending upon shape and size of these structures, several physical properties such as Electrical, Optical, Magnetic, etc. have been studied for above mentioned applications using Atomic Force Microscopy, X-Ray Photoelectron Spectroscopy, Raman Spectroscopy.
- Coming together of Nanotechnology and Bio-Engineering, when these surfaces have been interacted with biological molecules such as DNA, have lead to major findings in Bio-Transplants and Bio-Sensors.

Atomic Force Microscopy (AFM)



- AFM microscope is used for visualizing very small Nanostructures and Atoms on the surface.
- It works almost like 'A Blind Man with a Stick'. It has a very sharp needle which moves onto the surface, building up the map of nanostructures on the surface as it goes along.
- It provides information about the sample surface which is very useful for explaining various physical properties as mentioned in Introduction.
- Gerd Binnig and Heinrich Rohrer got the Nobel Prize in Physics in 1986 for the development of AFM.

X-Ray Photoelectron Spectroscopy (XPS)



- It is based on the principle of the famous Einstein Photoelectric Effect (1905).
- It is a surface sensitive spectroscopic technique that provides qualitative and quantitative information about the elemental composition, chemical state (Oxidation state, bonding), etc. of the elements that exists within a material.
- XPS spectra are obtained by irradiating a material with a beam of X-Rays while simultaneously measuring the Kinetic Energy and Number of Electrons that escape from the top of the surface (between 0-10nm) of the material being analyzed.
- It is a non-destructive technique as the energy of the X-ray which is use to get XPS spectra is in energy range of 1200-1400eV. (1eV=1.6x10⁻¹⁹Joules)
- Prof. Kei Siegbahn has been awarded Nobel Prize in Physics in 1981.

Raman Spectroscopy

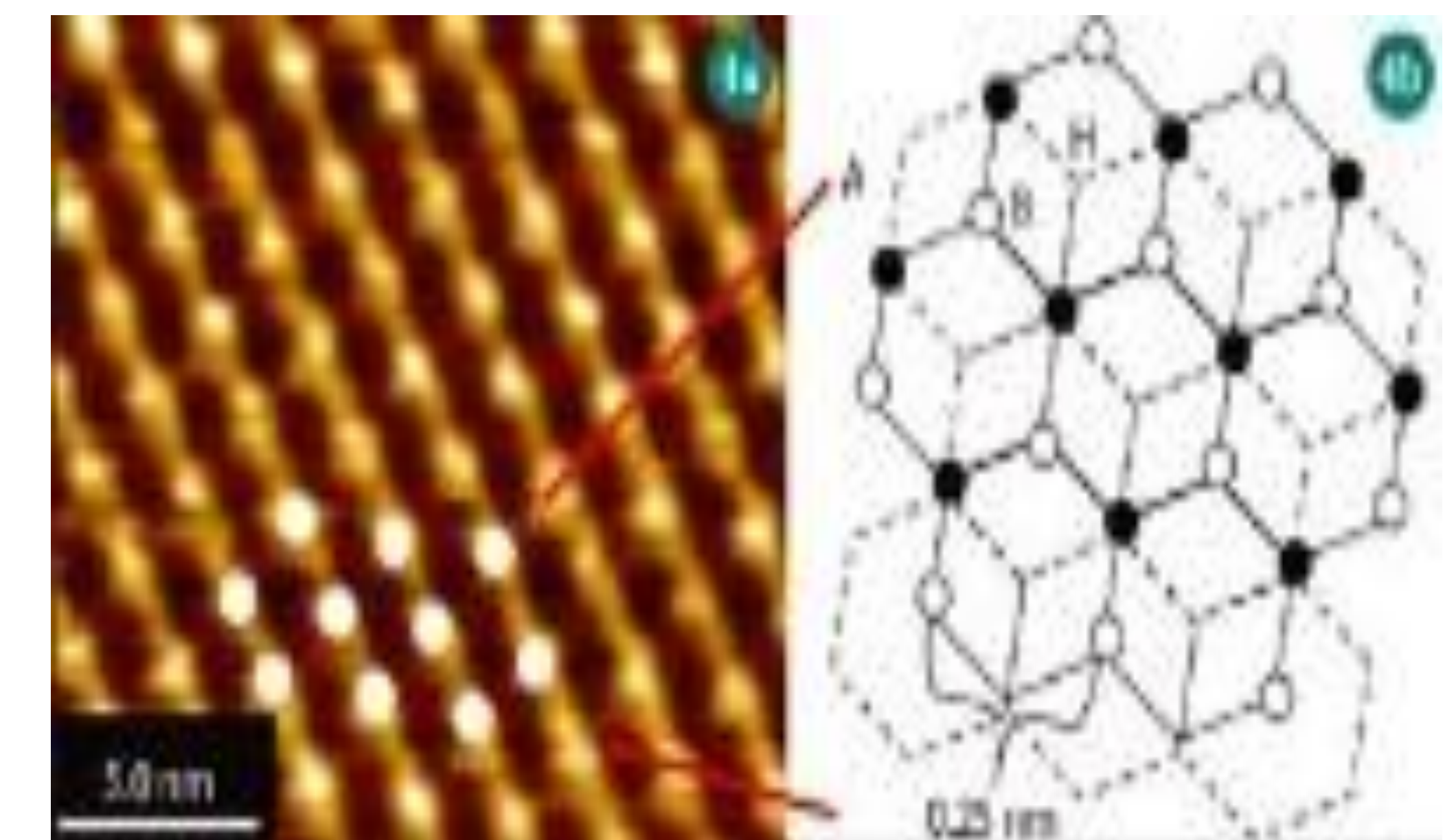


- It relies on inelastic scattering of monochromatic light usually from LASER. The theory has been developed by Adolf Smeakel in 1923.
- It is commonly used to provide a fingerprint by which the symmetry and nature of chemical bonds of all molecules can be identified, as Raman Scattering is very sensitive to these properties.
- We can also get information about the Crystal Orientation and its structure by using Raman Spectroscopy.
- Sir C.V. Raman, who observed inelastic scattering of light experimentally (along with K. S. Krishnan and independently by Grigory Landsberg and Lenoid Mandelstam), has got Nobel prize for Physics in 1930.
- Systematic pioneering theory of Raman effect was developed by Czechoslovak Physicist George Placzek between 1930 and 1934.

Key Findings

- Nanostructures grown on TiO₂ surfaces shows a reduction in Band Gap and enhanced absorption of visible light which can be used for Solar Cells, Photovoltaic, etc. [1, 2].
- When nanostructured TiO₂ surfaces have been interacted with DNA, enhanced Hydrophobicity has been observed which makes TiO₂ an important material for Bio-Transplants [3].
- Metal conjugated with DNA can be used as a sensor for Mercury contamination which can lead to several disorders in human body [4].
- Room temperature Ferromagnetism has been observed which can be used for future Spintronics applications [5].

Carbon Atoms on Graphite using AFM



Reference

1. Majumder et.al. Applied Physics Letters 98, 053105 (2011)
2. Solanki et.al Journal of Applied Physics 115 124306 (2014)
3. Majumder et.al. Applied Physics Letters 103, 063103 (2013)
4. Majumder et.al. Applied Physics Letters 94, 073110 (2009)
5. Majumder et.al. Applied Surface Science 256, 513 (2009)